TOSHIBA Transistor Silicon NPN Triple Diffused Type

# 2SD2414(SM)

High Current Switching Applications Power Amplifier Applications

• Low collector saturation voltage:  $V_{CE}$  (sat) = 0.5 V (max) (at I<sub>C</sub> = 4 A)

#### Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V <sub>CBO</sub>	100	V	
Collector-emitter voltage		V <sub>CEO</sub>	80	V	
Emitter-base voltage		V <sub>EBO</sub>	5	V	
Collector current		Ι <sub>C</sub>	7	А	
Base current		Ι <sub>Β</sub>	1	А	
Collector power dissipation	Ta = 25°C	Pc	1.5	W	
	Tc = 25°C	ГC	40		
Junction temperature		Тj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	

10.3MAX 1.32 10.6 MAX 5 5 ю Н 0.76 2.54 7 MAX 1. BASE 2. COLLECTOR (HEAT SINK) 3. EMITTER JEDEC \_\_\_\_ JEITA \_ TOSHIBA 2-10S2

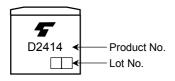
Weight: 1.4 g (typ.)

Unit: mm

**Electrical Characteristics (Ta = 25°C)** 

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I <sub>CBO</sub>	V <sub>CB</sub> = 100 V, I <sub>E</sub> = 0	—	_	5	μA
Emitter cut-off current		I <sub>EBO</sub>	V <sub>EB</sub> = 5 V, I <sub>C</sub> = 0	_	_	5	μA
Collector-emitter breakdown voltage		V (BR) CEO	I <sub>C</sub> = 50 mA, I <sub>B</sub> = 0	80	-	_	V
DC current gain		h <sub>FE (1)</sub>	V <sub>CE</sub> = 1 V, I <sub>C</sub> = 1 A	100	_	320	
		h <sub>FE (2)</sub>	V <sub>CE</sub> = 1 V, I <sub>C</sub> = 4 A	30	_	_	
Collector-emitter	ector-emitter saturation voltage $V_{CE (sat)}$ $I_C = 4 A$ , $I_B = 0.4 A$		_	0.25	0.5	V	
Base-emitter saturation voltage		V <sub>BE (sat)</sub>	I <sub>C</sub> = 4 A, I <sub>B</sub> = 0.4 A	_	0.9	1.4	V
Transition frequency		fT	V <sub>CE</sub> = 4 V, I <sub>C</sub> = 1 A	_	10	_	MHz
Collector output capacitance		C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz	-	200	_	pF
Switching time	Turn-on time	t <sub>on</sub>	20 µs Output Input $I_{B1}$ Output $I_{B2}$ $V_{CC} \approx 30 V$ $I_{B1} = -I_{B2} = 0.3 A, duty cycle ≤ 1%$	_	0.4	_	
	Storage time	t <sub>stg</sub>		_	2.5	_	μs
	Fall time	t <sub>f</sub>		_	0.5	_	

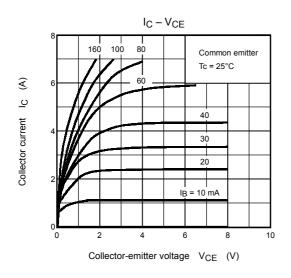
### Marking

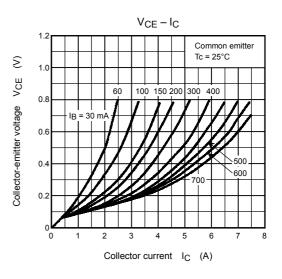


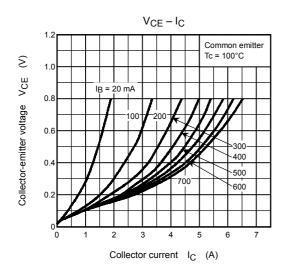
## Explanation of Lot No.

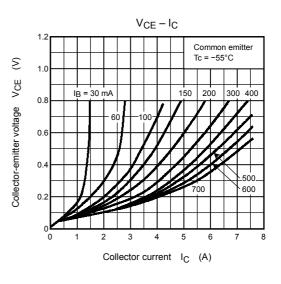
Month of manufacture (January to December are denoted by letters A to L respectively.) Year of manufacture (Last decimal digit of the year of manufacture)

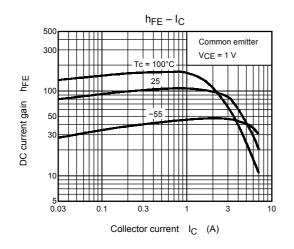
## **TOSHIBA**

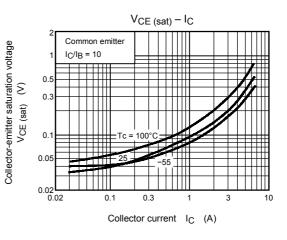




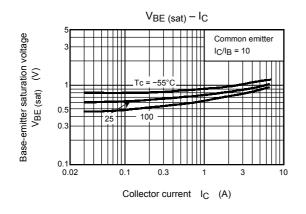


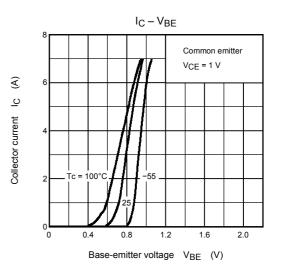






# **TOSHIBA**





Safe Operating Area IC max (pul 10 1 ms -IC max .(continu € 10 Collector current IC DC operation Tc = 25°C 100 ms 0.5 0.3 \*: Single nonrepetitive pulse Tc = 25°C Curves must be derated linearly with increase in temperature. VCEO max 0.1 3 5 10 50 30 100 Collector-emitter voltage  $V_{CE}$  (V)

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